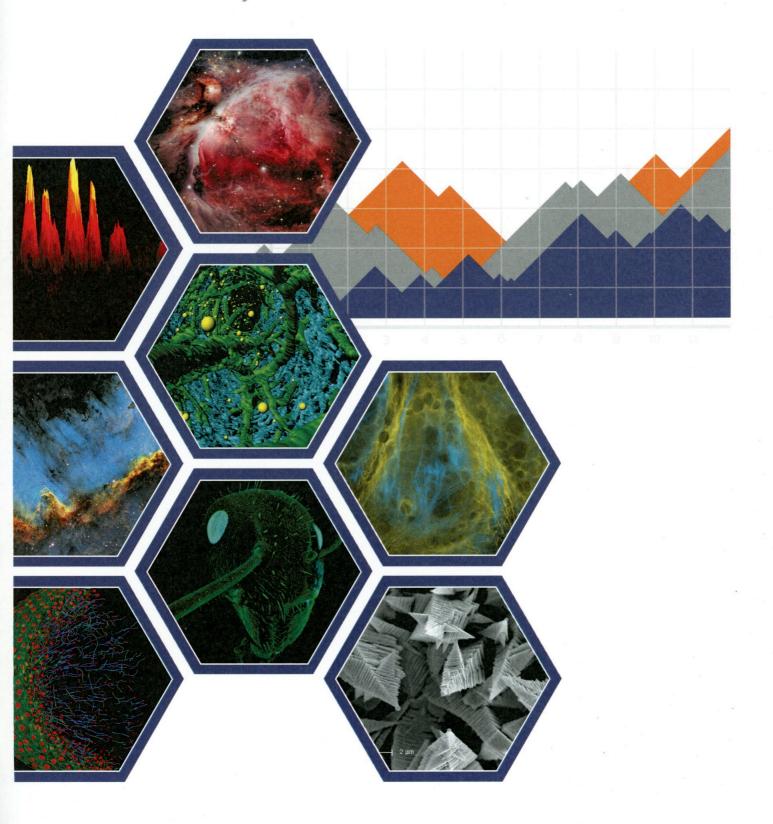
RMA# R62047 Feb-2019 BS05



# System Performance Booklet



Roudin HI Mon, Ø4 Feb 2019 Mf



discover new ways of seeing

### **Shipping Invoice**

Shipment No.

R62047

**Andor Order No** 

**Customer Order No:** 

R62047

F019025

**Despatch Date:** 

01-Feb-2019

AWB No.

1Z8W40070460624580

#### Shipped To:

SJSU RES. FOUND. MOSS LANDING UNIV. MARINE CTR 965 N. NIMITZ HIGWAY HONOLULU, HI 96817 **UNITED STATES** 

#### **Customs Information:**

Goods are part of an Optical Checking/Measuring Device

Harmonized No 90275000 Identification Code GBAND10BEL Goods are made in the UK Values are for Customs Purposes

#### UG-STD:

These goods are uncontrolled

to destination.

Goods re-exported may require an

export licence

	Description of Goods		USD		
NWR (S)	NON WARRANTY REPAIR		1,750.00	1	off
	DU934P-BR-DD CCD-20477 ✓		0.00	0	off
	VALUE FOR CUSTOMS USD 15000		0.00	0	off
	CPC 3151000 - IPR IP/0920/500/21		0.00	0	off
	HS CODE 9802004040 - 8525804000		0.00	0	off
			0.00	0	off
	TERMS: NET 30		0.00	0	off
	CONFIRM TO: HUE NGO		0.00	0	off
	END USER: MARK YARBROUGH		0.00	0	off
	EMAIL: yarbrough@mlml.calstate.edu		0.00	0	off
	PH #808-753-0664		0.00	0	off
	ANDOR CONTACT: SCOTT DEXTER		0.00	0	off
	**SHIP VIA UPS**	a a	0.00	0	off
Values are for o	customs purposes only	Total Value	1,750.00		USD



### **Returns Report**

Customer

ANDUSA Yarbrough/MLML

**Returns No** 

R62047

Classification

**NON WARRANTY** 

**Customer RMA No** 

None

**Equipment Details** 

Model

**Serial Number** 

Head

DU934P-BR-DD-9XT

CCD-20477

Card

**PSU** 

Multi 10

Other

**Reported Fault** 

Returning iKon-M camera for widow changes.

Camera parallel window to be replaced with WN35FS Broadband VUV-NIR Wedged windows, code- (BB-VV-NR)W.

**Diagnosis** 

Confirmed requested wedged window replacement required.

#### **Work Carried Out**

Wedged window installed.

Full system QC & new performance sheets completed: - Passed.

Receipt Date Work Complete Passed For Shipping Shipped

Date

22/08/2018

16/01/19

16/01/19

**Initials** 

**PMC** 

ΡJ

MB

<sup>\*</sup> In the case of Products which are upgraded, the old Model No / Serial No are bracketed first, followed by the new Nos:

<sup>\*\*</sup> Returns must be passed for shipping by the manufacturing manager and / or Sales Support



### **System Overview**

Description	Model	Reac	Seri	al Number	
CCD Head V	D U 9 ;	34P - BEX2-D	D-9XT CCI	0-20477	D Rate
TE Cooler performand	ce (*)	и ваюи	High	Ultra-high	xHA)
Accessories	Power Supp	ly Unit (PS -24)	m co Qui rea asi	PS -25	GIS OF I
1077		0.00		•	5
1528	SO- I	LM-	MFL-	1 x2	a
Serial/Batch Numb	er			by	8
Other					2

Sensor types are defined in Table 1 using the last two letters in box Model Number.

#### **CCD Details**

Manufac	turer / Model No.	Pixels	Serial Number
E2V	CCD47-10	1024x1024, 13μm x 13μm	12262-17-08
E2V	CCD57-10	512x512, (FT), 13μm x 13μm	
E2V	CCD77-00	512x512, 24μm x 24μm	888.00

Special Feature	(*)		(*)
NIMO 2000	•	Custom Mounting Flange	
Fringe Suppression		Custom Cables	
Shielded Anti-Blooming			

Window Variant	(*)	(*)
VUV-UV Parallel	NUV-Enhanced Parallel	
Broadband VUV-NIR Wedged	Broadband VUV-NIR Parallel	
Broadband VIS-NIR Wedged	Broadband VIS-NIR Parallel	
VIS-NIR Enhanced Wedged	Bose-Einstein 780nm Wedged	
None	Other	

CHECKED

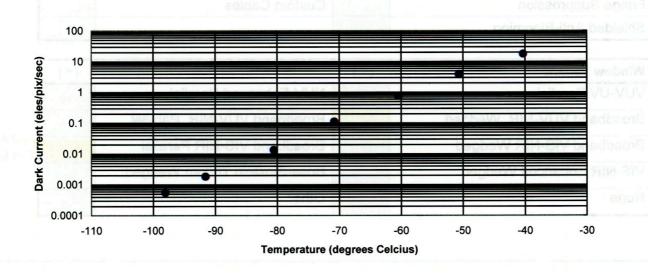


### **Summary of System Test Data**

#### Readout Noise +1 and Base Mean Level

A/D Rate (MHz All 16 bit)	Preamp setting	CCD Sensitivity ◆3 eles per A/D count	Single Pixel Noise electrons	Full Vert Bin Noise electrons	Base Level    (Counts)
5	x1	6.7	34.0	33.1	1077
5	x2	3.6	19.1	18.3	1528
5	x4	1.7	14.1	13.7	2786
3	x1	6.2	20.5	19.9	1185
3	x2	3.1	13.2	13.0	2200
3	x4	1.4	10.2	9.8	3879
ad doo	x1	5.5	11.4	11.0	944
1	x2		8.3	8.1	1904
1 .	x4	1.3	6.8	6.5	3878
0.05	x1	5.4	5.2	5.2	548
0.05	x2	2.8	4.1	4.1	1493
0.05	x4	1.3	3.5	3.5	3437
Satura	tion Signal p	er pixel	140999	Electron	ns/pixel

#### **CCD Dark Current**



Minimum Dark Current Achievable ◆4	0.000522	electro	ns/pixel/s	ec
@ Sensor Temperature of ◆5	-98.068	°C	16	°C cooling Water
		With PS-25		
CCD Dark Current Uniformity better than +6	0.3788	electrons/pixel/sec		sec



#### **Linearity and Uniformity**

Linearity better than ◆7	1	% over 16 bits
Response Uniformity better than ◆8	1.70	% 15 hours an ioue Le

#### **Response Defects**

Centroid	Number of Pixels	Centroid	Number of Pixels
( X , X ,			
White/Black Columns ◆10	Column numbe	ers indicated	x x x
Trap ♦11	Date Committee	(X,Y) (	x , x )

#### **Dark Current Defects**

Centroid	Number of Pixels	Centroid	Number of Pixels
( X , X ) ( X , X ) ( , ) ( , )	X		



#### **Test Conditions**

Readout Noise tested at	-80	°C with	16	°C water
Base Mean Level measured at	-80	°C with	16	°C water
Dark Current Uniformity tested at	-65	°C with	16	°C water
Blemishes tested at	-65	°C with	16	°C water

**Custom Testing** 

WN35FS Broadband VUV-NIR Wedged window fitted as per customer request.

**System Passed for Shipping** 

Signed

Date

PATRICK MCCANN

18™ OCTOBER 2018

Hardware	HEADBOARD	FPGA
Version #	AF	20.24
Shipping Software	SOLIS	SDK
Version #		
Testing Software	SOLIS	SDK
Version #	4.30.30008.0	2.102.30008.0

# $\nabla$ Table 1; Key code to define the meanings of the last two letters in the Model Number

Sensor Options			
OE	Open electrode	BU2	Back Illuminated (BI) + 250nm UV optimised
FI	Front illuminated (FI)	BU	BI + UV (350nm) optimised
UV	FI+UV coating	BV	BI + VIS (550nm) optimised)
FO	FI + Fibre optic	BR-DD	BI + NIR +deepdepletion
FI-DD	FI + deep depletion	BN	BI with no AR coating



#### **Performance Notes**

- Readout Noise is measured for both single pixel (SP) and fully vertically binned (FVB) with the CCD in darkness at temperature indicated and minimum exposure time. Noise values will change with pre-amplifier gain selection [PAG].
- ♦2 Average electronic DC offset for CCD in darkness at temperature indicated and minimum exposure time under dark conditions measured by single pixel (SP) for imaging systems and by (FVB) for spectroscopic systems.
- Sensitivity is calculated in photoelectrons per A/D count from measurements of the Photon Transfer Curve.
- Dark current falls exponentially with temperature. However, for a given temperature the actual dark current can vary by more than an order of magnitude from device to device. The devices are specified in terms of minimum dark current achievable rather than minimum temperature.
- ◆5 Minimum temperature achieved for thermoelectric (TE) cooler set to maximum value with water cooling
- RMS (root mean square) deviation of dark current for fully binned operation for spectroscopic cameras, or full resolution image for imaging cameras, under dark conditions at temperature indicated (pixel/column defects not included). This variation is mainly cosmetic since it is fully subtractable without significant loss of performance.
- ◆7 Linearity is measured from a plot of Counts vs. Signal over the 16 bit dynamic range. Linearity is expressed as a %age deviation from a straight line fit. This quantity is not measured on individual systems.
- RMS (root mean square) deviation from the average response of the CCD in full resolution image for imaging cameras, illuminated with uniform white light (defects not included).
- ♦9 White/black pixels have signals >25% above/below the average (25% contrast) with uniform illumination across the sensor.
- ◆10 A black column is defined as having ≥ 10 black pixels for imaging cameras.
- Pixels which absorb charge as it is clocked through the defective area. When the light source is switched off, the signal from the trap appears to drop off more slowly than the signal from the surrounding pixels.
- ♦12 Hot spots are counted if they exhibit >50 times the maximum specified dark current at the test temperature indicated.
- ♦13 A column is considered defective if >10 pixels are affected, or if the column exhibits >2 times the maximum specified dark current at the test temperature indicated.